

Features:

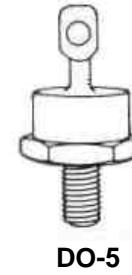
- Very Low Forward Voltage (0.6V at 60A, 125°C)
- Low Recovered Charge
- Rugged Package Design (DO-5)
- High Efficiency for Low Voltage Supplies
- Low Thermal Resistance (1.0°C/W)
- High Surge Current (1000A)
- Low Reverse Current (<50mA at rated V_R at 125°C)

**USD520
USD535
USD545**

**150 Amp Pk,
Up to 45V
POWER SCHOTTKY
RECTIFIERS**

Description:

This series of Schottky barrier power rectifiers is ideally suited for output rectifiers and catch diodes in low voltage power supplies. The Microsemi high conductivity design, using a heavy copper top post and 4 point crimp, ensures cool thermal operation and low dynamic impedance. Rugged design absorbs stress that can damage glass-to-metal seal during installation and use.



Absolute Maximum Ratings:

Working Peak Reverse Voltage, V_{RWM}
 DC Blocking Voltage, V_R
 Peak Repetitive Surge Voltage, V_{RSM} @ I_{RM}
 Peak Repetitive Forward Current
 (Rated V_{R1} Square Wave, 20KHz,
 50 percent Duty Cycle), I_{FRM}
 Average Rectified Forward Current, $I_{F(AV)}$
 Non-repetitive Peak Surge Current (8.3mS), I_{FSM}
 Peak Reverse Transient Current, I_{RT}
 Storage Temperature Range, T_{STG}
 Operating Junction Temperature, T_j
 Thermal Resistance Junction-to-Case, $R\theta_{JC}$

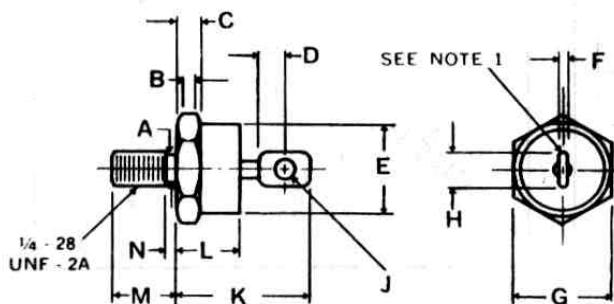
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Working Peak Reverse Voltage, V_{RWM}	20V	35V	45V
DC Blocking Voltage, V_R	20V	35V	45V
Peak Repetitive Surge Voltage, V_{RSM} @ I_{RM}	24V	42V	54V
Peak Repetitive Forward Current (Rated V_{R1} Square Wave, 20KHz, 50 percent Duty Cycle), I_{FRM}	150A (at $T_c = 115^\circ C$)	75A (at $T_c = 115^\circ C$)	1000A
Average Rectified Forward Current, $I_{F(AV)}$			2A
Non-repetitive Peak Surge Current (8.3mS), I_{FSM}			-55° to +200° C
Peak Reverse Transient Current, I_{RT}			+175° C
Storage Temperature Range, T_{STG}			1° C/W
Operating Junction Temperature, T_j			
Thermal Resistance Junction-to-Case, $R\theta_{JC}$			

Electrical Characteristics ($T_{CASE} = 25^\circ C$)

Characteristic	Symbol	Limit	Units	Conditions
		USD545		
Maximum Instantaneous Reverse Current	i_R	20 (50)	mA	$V_R = V_{RWM}$ $(T_c = 125^\circ C)$ Pulse Width = 300μs Duty Cycle = 1 percent
Maximum Instantaneous Forward Voltage	V_F	0.50 0.68 0.60	V	$i_F = 10A, T_c = 25^\circ C$ $i_F = 60A, T_c = 25^\circ C$ $i_F = 60A, T_c = 125^\circ C$
Maximum Capacitance	C_t	4000	pF	$V_R = 5.0V$
Maximum Voltage Rate of Change	dv/dt	1000	V/μS	$V_R = \text{rated}$

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MECHANICAL SPECIFICATIONS:



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	ins.	mm
A	.225 ± .005	5.72 ± 0.13
B	.060 MIN.	1.52 MIN.
C	.156 ± .020	3.96 ± 0.51
D	.156 MIN. FLAT	3.96 MIN. FLAT
E	.667 DIA. MAX.	16.94 DIA. MAX.
F	.090 MAX.	2.29 MAX.
G	.677 ± .010	17.20 ± 0.25
H	.375 MAX.	9.53 MAX.
J	.140 MIN. DIA.	3.56 MIN. DIA.
K	1.000 MAX.	25.40 MAX.
L	.450 MAX.	11.43 MAX.
M	.438 ± .015	11.13 ± 0.38
N	.078 MAX.	1.98 MAX.

Notes:

1. Cathode is stud.
2. All metal surfaces tin plated.
3. Maximum unlubricated stud torque: 30 inch pounds (35 kg. cm).
4. Angular orientation of terminal is undefined.

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